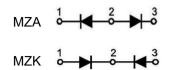


# **Fast Recovery Diode Module**

Symbol	Value	Unit
V <sub>R</sub>	600	V
IFAV	400	Amp





#### **Features**

- Ultra-fast reverse recovery time
- Soft reverse recovery characteristics
- Low reverse recovery loss
- High system power density

# **Applications**

- Inversion welder
- Power factor correction(PFC)circuit
- Plating power supply
- Ultrasonic cleaner and welder
- Converter & chopper

## **Maximum Ratings**

Symbol	Item	Conditions	Values	Unit	
VR	Maximum D.C. Reverse Voltage		600	V	
VRRM	Maximum Repetitive Reverse Voltage		000	<b>V</b>	
lfav	Average Forward Current	Rectangular , d=0.5, Tc=96℃,Per Leg	200	А	
		Rectangular , d=0.5, Tc=96℃,Per Module	400		
IFRMS	RMS Forward Current	Tc=96℃, Per Leg	280	Α	
lгsм	Non-Repetitive Peak Surge Current	t = 50Hz(10ms), V <sub>R</sub> = 0V,Per Leg,Tj = 25℃	2000	Α	
l²t	Circuit Fusing Consideration	t = 10ms T <sub>j</sub> =25°C	20000	A <sup>2</sup> s	
Viso	Isolation Breakdown Voltage	AC 50Hz/60Hz; R.M.S; 1min	3000	V	
Ptot	Total Power Dissipation	T <sub>j</sub> =25°C	694	W	
Tj	Operating Junction Temperature		-40 to +150	°C	
Tstg	Storage Temperature		-40 to +125	°С	
Mt	Mounting Torque	To Terminals(M6)	5±15%	NI	
Ms	- mounting forquo	To Heatsink(M6)	5±15%	N·m	
Weight	Module (Approximately)		185	g	

## **Thermal Characteristics**

Symbol	Item	Conditions	Values	Unit
Rth(j-c)	Thermal Impedance, Max	Junction to Case(Per Leg)		°C/W

www.hypersemi.com.cn - 1 -



## **Electrical Characteristics**

Symbol	Item	Conditions	Values			11
			Min.	Тур.	Max.	Unit
V <sub>FM</sub>	Forward Voltage Drop Per Leg, Max	Tj=25℃ , IF=200A	_	_	1.6	V
	Repetitive Peak Reverse Current	Tj = 25℃ VR = VRRM	_	_	0.2	
IRRM	Per Leg, Max	Tj = 150℃ VR = VRRM	-	-	10	mA
t <sub>rr</sub>	Typical Reverse Recovery Time Per Leg	I <sub>F</sub> = 0.5A, I <sub>R</sub> = -1A, I <sub>RR</sub> = -0.25A	_	140	_	ns
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> =200A,V <sub>R</sub> =300V, di <sub>F</sub> /dt=-200A/μs, T <sub>j</sub> = 25°C	_	140	_	ns
<b>I</b> RM	Maximum Reverse Recovery Current	$I_F$ =200A, $V_R$ =300V, di <sub>F</sub> /dt=-200A/ $\mu$ s, $T_j$ = 125°C	-	15	_	Α
t <sub>rr</sub>	Reverse Recovery Time	T <sub>j</sub> = 125°C	-	260	_	ns
<b>I</b> RM	Maximum Reverse Recovery Current	T <sub>j</sub> = 125°C	-	25	_	Α
V <sub>T0</sub>	Threshold Voltage, for power loss calculation only	I <sub>F</sub> = 0.5A, I <sub>R</sub> = -1A, I <sub>RR</sub> = -0.25A		0.7		V
r <sub>T</sub>	Slope Resistance, for power loss calculation only			2.0		m $Ω$

# **Characteristics Diagram**

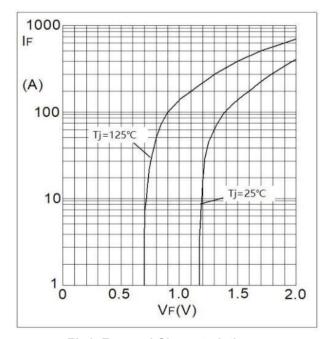


Fig1. Forward Characteristics

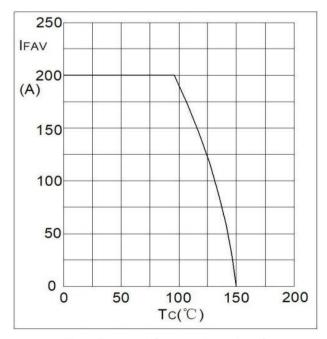


Fig2. Forward Current Derating Curve

www.hypersemi.com.cn -2-

# HF15MZA-K400N6X100 Fast Recovery Diode Module

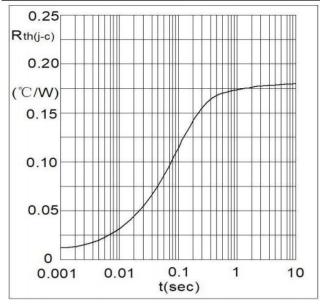


Fig3. Transient Thermal Impedance

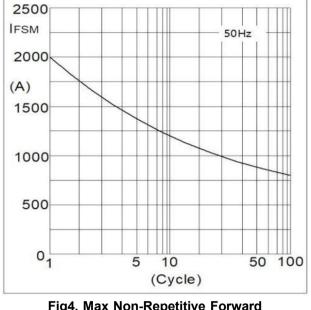


Fig4. Max Non-Repetitive Forward Surge Current

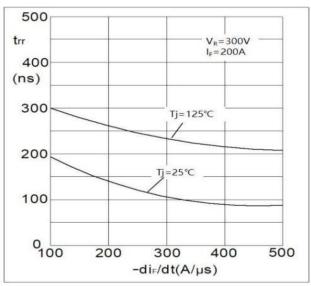


Fig5. Reverse Recovery Time VS diF/dt

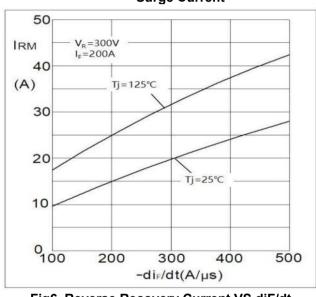


Fig6. Reverse Recovery Current VS diF/dt

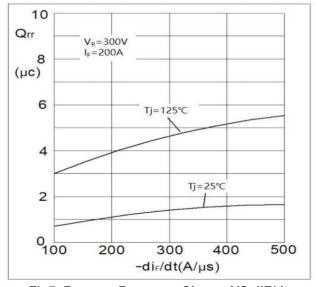
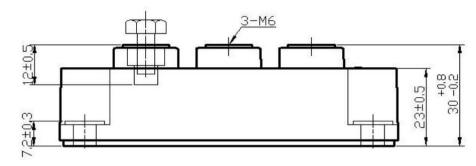


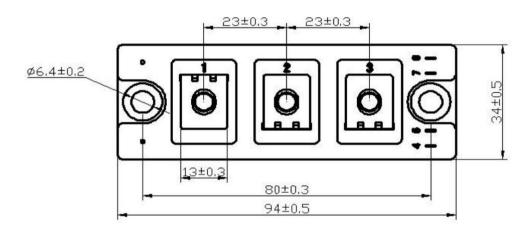
Fig7. Reverse Recovery Charge VS diF/dt

www.hypersemi.com.cn - 3 -



#### Package Outlines(Dimensions in mm)





#### \*Important Usage Information and Disclaimer

The specifications of Zhuhai Hypersemi Co., Ltd. products are not guarantees of product characteristics. They reflect typical performance expected in standard applications, which may vary with specific uses. Users must conduct prior testing for their applications and make necessary adjustments.

Users are responsible for the safety of applications utilizing our products and must implement adequate safety measures to prevent physical injury, fire, or other risks in case of product failure. It is the user's duty to ensure that application designs comply with all applicable laws and standards. Our products must not be used in any applications where a product failure could reasonably result in personal injury, unless specifically authorized in a signed document by Zhuhai Hypersemi Co., Ltd.

No representations or warranties are made regarding the accuracy or completeness of this information, including any claims of non-infringement of third-party intellectual property rights. Zhuhai Hypersemi Co., Ltd. assumes no liability for any applications or uses of its products and does not grant any licenses to its intellectual property rights or those of others. We also make no claims regarding non-infringement of third-party intellectual property rights that may arise from applications.

Due to technical requirements, our products may contain hazardous substances. For details, please contact your nearest sales office. This document replaces all previous information and may be updated. We reserve the right to make changes.

www.hypersemi.com.cn - 4 -